



APPLIED PHYSICS I

December 16

Computer Engineering (Semester 1)

Total marks: 80

Total time: 3 Hours

INSTRUCTIONS

(1) Question 1 is compulsory.

(2) Attempt any **three** from the remaining questions.

(3) Draw neat diagrams wherever necessary.

Q.1](a)What are crystal imperfections? Mention any two significance of it. (3)

Q.1](b)Write Schrodinger's time dependent and time independent wave equations of matter waves in one dimensional and state physical significance of these equations. (3)

Q.1](c)Draw the I-V characteristics of a photo-diode. What is meant by a dark current? (3)

Q.1](d)Define super conductivity and critical temperature. Plot the variation of resistance versus temperature in case of superconducting state of the material. (3)

Q.1](e)What is reverberation time? Discuss Sabine formula (3)

Q.1](f)State 'magnetostriction effect'. Mention any two applications of ultrasonic waves (3)

Q.1](g)Calculate conductivity of a germanium sample if a donor impurity atoms are added to the extent to one part in 10^6 germanium atoms at room temperature.

Assume that only one electron of each atom takes part in conduction process

Given:-Avogadro's number= 6.022×10^{23} atom/gm-mol

Atomic weight of Ge=72.6

Mobility of electrons= $3800 \text{cm}^2/\text{volts sec}$

Density of Ge= 5.32 gm/cm^3 (3)

Q.2](a)Describe with necessary theory the Davisson and German establishing wave nature of electrons.

Calculate the de-Broglie wavelength of an alpha particle accelerating through a potential difference of 200volts



Given:-mass of alpha particles= 6.68×10^{-27} kg (8)

Q.2](b) Define the term drift current and mobility of a charge carriers. Calculate the current product in a germanium sample of area of cross section 1 cm^2 and thickness 0.01 mm , when a potential difference of 2 V is applied across it. (7)

Given:-the concentration of free electron in germanium is $2 \times 10^{19} / \text{m}^3$ and mobilities of electrons and holes are $0.36 \text{ m}^2 / \text{volts sec}$ and $0.17 \text{ m}^2 / \text{volts sec}$ respectively.

Q.3](a) Draw and explain the unit cell of sodium chloride (NaCl) crystals. Determine effective number of NaCl molecules per unit cell and coordination number. (8)

Q.3](b) State applications of Hall effect. In a Hall effect experiment a potential difference of $4.5 \mu\text{V}$ is developed across a foil of zinc of thickness 0.02 mm , when a current of 1.5 A is carrying in a direction perpendicular to applied magnetic field of 2 tesla .

Calculate (a) Hall coefficient for zinc (b) Concentration of electrons (7)

Q.4](a) Discuss formation of Cooper pairs and energy gap in superconductor on the basis of BCS theory. (5)

Q.4](b) State any five factors affecting the acoustics of the building and give the remedies for each. (5)

Q.4](c) An ultrasonic pulse of 0.09 Hz sends down towards the sea-bed which returns after 0.55 sec . The velocity of ultrasonic waves in sea water is 1800 m/sec . Calculate the depth of sea and wavelength of ultrasonic pulse (5)

Q.5](a) How does the position of Fermi energy level change with increasing doping concentration in p-type semi-conductors? Sketch the diagram. (5)

Q.5](b) Explain analysis of crystal structure using Bragg's X ray spectrometer. (5)

Q.5](c) Find the minimum energy of neutron confined to a nucleus of size of the order of 10^{-14} m .

Given mass of neutron = $1.675 \times 10^{-27} \text{ kg}$. (5)

Q.6](a) Calculate the critical radius ratio of an ionic crystal in octahedral coordination. What is the maximum size of cation in octahedral configuration, when size of anion is 2.02 \AA ? (5)

Q.6](b) What do you mean by group and phase velocity? Show that the de-Broglie group velocity associated with the wave packet is equal to the velocity of the particle. (5)

Q.6](c) Explain the formation of potential barrier across the unbiased p-n junction region. (5)